Super Fast Recovery Diode

RFV8TG6S Data Sheet

Serise

Standard Fast Recovery

Application

General rectification

For PFC

(CCM: Continuous Current Mode)

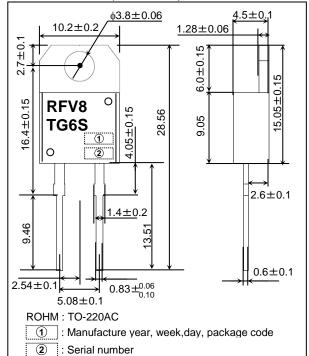
Features

- 1) Hyper fast recovery / Hard recovery type
- 2) Ultra low switching loss
- 3) High current overload capacity

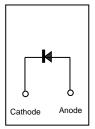
Construction

Silicon epitaxial planar type

● **Dimensions** (Unit: mm)



Structure



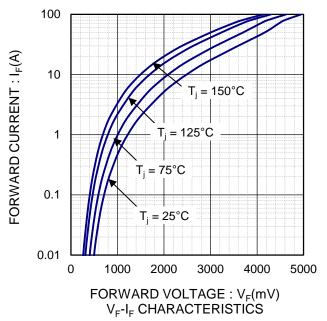
● Absolute Maximum Ratings (T_a= 25°C)

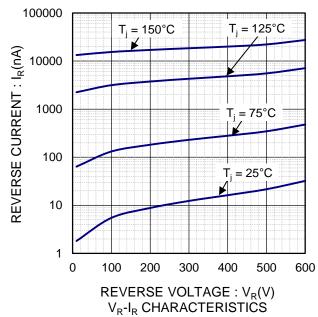
Parameter	Symbol	Conditions	Limits	Unit
Repetitive peak reverse voltage	V_{RM}	Duty≦0.5	600	V
Reverse voltage	V_R	Direct reverse voltage	600	V
Average current	l _o	60Hz half sin wave , resistive load	8	Α
Non-repetitive forward surge current	I _{FSM}	60Hz half sin wave, one cycle, non-repetitive at $\rm T_{\rm j}{=}25^{\circ}C$	100	Α
Operating junction temperature	Tj	-	150	°C
Storage temperature	T _{stg}	-	-55 to +150	°C

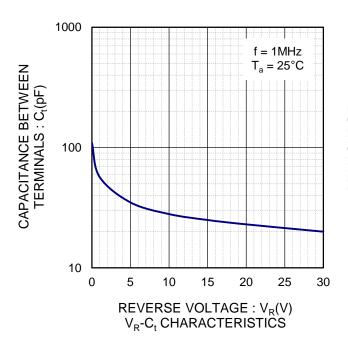
●Electrical Characteristics (T_j = 25°C)

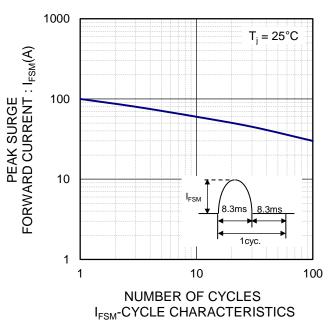
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Forward voltage	V _F	I _F =8A	T _j =25°C	1.6	2.3	2.8	V
			T _j =125°C	-	1.55	-	V
Reverse current	I _R	V _R =600V	T _j =25°C	-	0.03	10	μΑ
			T _j =125°C	-	5	200	μΑ
Reverse recovery time	trr	I _F =0.5A, I _R =1A, Irr=0.25×I _R		-	15	25	ns
		$I_F=8A$, $V_R=400V$, $dI_F/dt=-200A/\mu s$		-	25	45	ns
Reverse recovery current	I _{Rp}	I _F =8A, V _R =400V	T _j =125°C	-	5.5	-	Α
Reverse recovery charges	Qrr	dI _F /dt=-200A/μs		-	150	-	nC
Forward recovery time	tfr	I _F =8A, dI _F /dt=100A/μs,		-	125	-	ns
Forward recovery voltage	V_{Fp}	$V_{FR}=1.1xV_{Fmax}$		-	4.5	-	V
Thermal resistance	R _{th} (j-a)	Junction to ambient		-	-	2.5	°C/W
	R _{th} (j-c)	Junction to case		-	-	1.5	°C/W

•Electrical Characteristic Curves

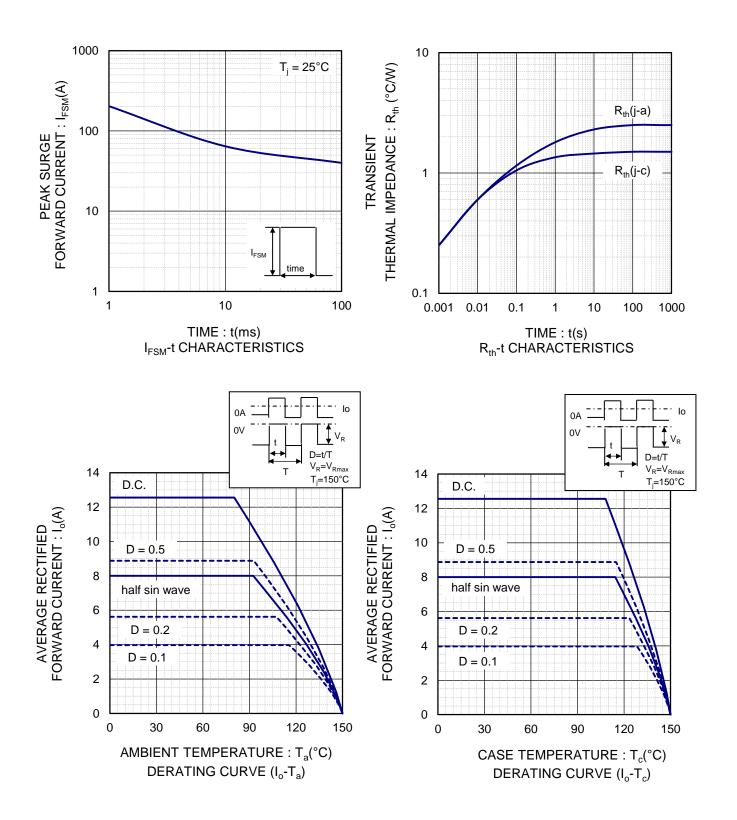




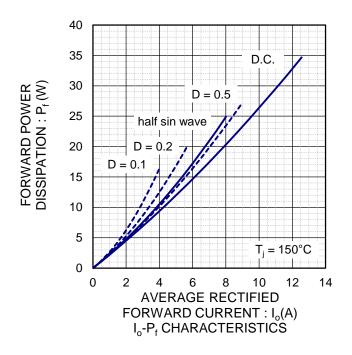


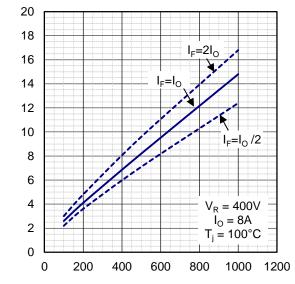


•Electrical characteristic curves

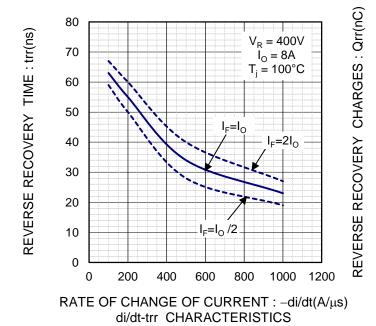


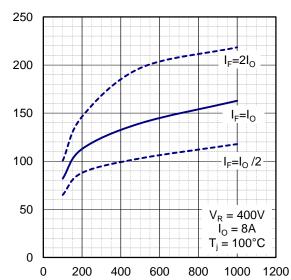
•Electrical characteristic curves





RATE OF CHANGE OF CURRENT : $-di/dt(A/\mu s)$ $di/dt-I_{Rp}$ CHARACTERISTICS

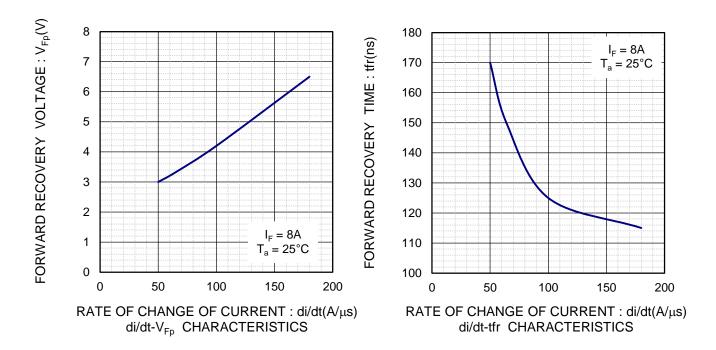




RATE OF CHANGE OF CURRENT : -di/dt(A/μs) di/dt-Qrr CHARACTERISTICS

REVERSE CURRENT PEAK: IRD (A)

•Electrical characteristic curves



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